TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX00FT,TC74VCX00FK

Low-Voltage Quad 2-Input NAND Gate with 3.6-V Tolerant Inputs and Outputs

The TC74VCX00FT/FK is a high-performance CMOS 2-input NAND gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

All inputs are equipped with protection circuits against static discharge.

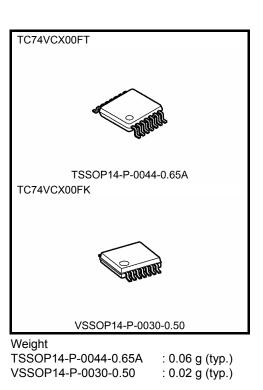
Features (Note)

- Low-voltage operation: VCC = 1.2~3.6 V
- High-speed operation: $t_{pd} = 2.8 \text{ ns} (\text{max}) (V_{CC} = 3.0 \sim 3.6 \text{ V})$

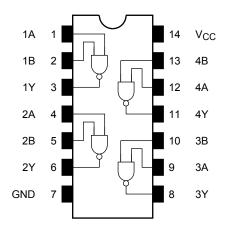
 $t_{pd} = 3.7 \text{ ns} (\text{max}) (V_{CC} = 2.3 \sim 2.7 \text{ V})$

- $t_{pd} = 7.4 \text{ ns} (\text{max}) (V_{CC} = 1.65 \sim 1.95 \text{ V})$
- $t_{pd} = 14.8 \text{ ns} (\text{max}) (V_{CC} = 1.4 \sim 1.6 \text{ V})$
- $t_{pd} = 37.0 \text{ ns} (max) (V_{CC} = 1.2 \text{ V})$
- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
 - $: I_{OH}/I_{OL} = \pm 18 \text{ mA} (\text{min}) (V_{CC} = 2.3 \text{ V})$
 - $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.65 \text{ V})$ $: I_{OH}/I_{OL} = \pm 2 \text{ mA (min)} (V_{CC} = 1.4 \text{ V})$
- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$
 - Human body model $\ge \pm 2000 \text{ V}$
- Package: TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs

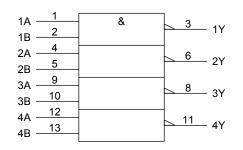
Note: Electrical Characteristics of Vcc=1.5±0.1V and 1.2V apply only to products whose Lot Code is over "3 12".



Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inp	uts	Outputs
А	В	Y
L	L	Н
L	Н	н
Н	L	Н
Н	Н	L

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~4.6	V
	Varia	-0.5~4.6 (Note 2)	V
DC output voltage	Vout	-0.5~V _{CC} + 0.5 (Note 3)	
Input diode current	IIК	-50	mA
Output diode current	I _{OK}	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: $V_{CC} = 0 V$
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	1.2~3.6	V	
Input voltage	V _{IN}	-0.3~3.6	V	
Output voltage	Vout	0~3.6 (Note 2)	V	
Output voltage	VOUT	0~V _{CC} (Note 3)		
		±24 (Note 4)	mA	
Output current		±18 (Note 5)		
Output current	I _{OH} /I _{OL}	±6 (Note 6)	ША	
		±2 (Note 7)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Note 4:	$V_{CC} = 3.0 \sim 3.6 V$
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- Note 5: $V_{CC} = 2.3 \sim 2.7 \text{ V}$
- Note 6: $V_{CC} = 1.65 \sim 1.95 \text{ V}$
- Note 7: $V_{CC} = 1.4 \sim 1.6 V$
- Note 8: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, 2.7 V < V_{CC} \leq 3.6 V)

Charact	orietice	Symbol	Tos	t Condition		Min	Мах	Unit
Characte	ensues	Symbol			V _{CC} (V)	IVIIII	IVIAX	Unit
Input voltage	H-level	VIH		—		2.0		V
input voltage	L-level	V _{IL}	—		2.7~3.6	_	0.8	v
H-level			$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}		$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	V
				I _{OH} = -24 mA	3.0	2.2	_	
		level V _{OL}	V _{IN} = V _{IH}	$I_{OL} = 100 \ \mu A$	2.7~3.6	_	0.2	
	Lloval			$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	L-IEVEI			I _{OL} = 18 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage cur	rent	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.7~3.6	_	±5.0	μA
Power-off leakage	e current	I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6	V	0	_	10.0	μA
	current	Icc	$V_{IN} = V_{CC}$ or GND	V _{IN} = V _{CC} or GND			20.0	
Quiescent supply current	100	$V_{CC} \leq V_{IN} \leq 3.6 \text{ V}$		2.7~3.6		±20.0	μA	
Increase in I _{CC} per input		Δl _{CC}	$V_{IH} = V_{CC} - 0.6 \ V$		2.7~3.6	_	750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characte	arietice	Symbol	Tos	t Condition		Min	Max	Unit
Characte	115005	Symbol			V _{CC} (V)	IVIIII	Max	Onit
Input voltage	H-level	VIH		_		1.6	_	v
input voltage	L-level	V _{IL}		_	2.3~2.7	_	0.7	v
				I _{OH} = -100 μA	2.3~2.7	V _{CC} - 0.2	_	
H-level	H-level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -6 mA	2.3	2.0		
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				I _{OH} = -18 mA	2.3	1.7		
			V _{IN} = V _{IH}	$I_{OL} = 100 \ \mu A$	2.3~2.7	_	0.2	
	L-level	V _{OL}		$I_{OL} = 12 \text{ mA}$	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage cur	rent	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.3~2.7	_	±5.0	μA
Power-off leakage current I _{OFF} V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μA			
			$V_{IN} = V_{CC} \text{ or } GND$		2.3~2.7	_	20.0	
Quiescent supply	current	Icc	$V_{CC} \stackrel{\scriptscriptstyle \leq}{=} V_{IN} \stackrel{\scriptscriptstyle \leq}{=} 3.6 \ V$		2.3~2.7	_	±20.0	μA

DC Characteristics (Ta = –40 to 85°C, 1.65 V \leq V_{CC} < 2.3 V)

Characte	pristics	Symbol	Test C	ondition		Min	Мах	Unit
Character		Cymbol	10010			IVIIII	Wax	Onic
Input voltage	H-level	VIH	—		1.65~2.3	$0.65 \times V_{CC}$		V
L-level	VIL	_		1.65~2.3		$0.2 \times V_{CC}$	v	
H-level	H-level	Vон	V_{OH} $V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -100 μA	1.65	V _{CC} - 0.2		v
Output voltage				I _{OH} = -6 mA	1.65	1.25	_	
	L-level	Vai		I _{OL} = 100 μA	1.65	_	0.2	
	L-level	V _{OL}	$V_{IN} = V_{IH}$ $I_{OL} = 6 \text{ mA}$		1.65	_	0.3	
Input leakage cur	rent	I _{IN}	V _{IN} = 0 to 3.6 V		1.65~2.3	_	±5.0	μA
Power-off leakage	Power-off leakage current I _{OFF} V _{IN} , V _{OUT} = 0 to 3.6 V			0	_	10.0	μA	
Quiescent supply current		$V_{IN} = V_{CC}$ or GND		1.65~2.3	_	20.0		
Quiescent supply	Current	Icc	$V_{CC} \leq V_{IN} \leq 3.6 \text{ V}$		1.65~2.3		±20.0	μA

DC Characteristics (Ta = –40 to 85°C, 1.4 V \leq V_{CC} < 1.65 V)

Characte	arietice	Symbol	Test	Condition		Min	Мах	Unit
Characte	513003	Symbol	1631			IVIIII	Max	Onit
Input voltage	H-level	V _{IH} —		1.4~1.65	$\begin{array}{c} 0.65 \times \\ V_{CC} \end{array}$	_	v	
input voltage	L-level	V _{IL}	—		1.4~1.65	_	$\begin{array}{c} 0.05 \times \\ V_{CC} \end{array}$, in the second se
H-level	H-level	evel V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -100 μA	1.4~1.65	V _{CC} - 0.2	_	V
Output voltage				$I_{OH} = -2 \text{ mA}$	1.4	1.05	_	
	L-level			$I_{OL} = 100 \ \mu A$	1.4~1.65	_	0.05	
		V _{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 2 \text{ mA}$	1.4	_	0.35	
Input leakage cur	rent	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.4~1.65	_	±5.0	μA
Power-off leakage	Power-off leakage current I _{OFF} V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μA		
Quiescent supply current			$V_{IN} = V_{CC}$ or GND		1.4~1.65	_	20.0	
Quiescent suppry	current	Icc	$V_{CC} \stackrel{\scriptscriptstyle \leq}{=} V_{IN} \stackrel{\scriptscriptstyle \leq}{=} 3.6 \ V$	$V_{CC} \leq V_{IN} \leq 3.6 \text{ V}$		—	±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.2 V \leq V_{CC} < 1.4 V)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH	—		1.2~1.4	$0.8 \times V_{CC}$	_	V
Input voltage		VIL	_	_	1.2~1.4		$0.05 \times V_{CC}$	v
Output voltage	H-level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -100 \ \mu\text{A}$		V _{CC} - 0.1	_	V
	L-level	V _{OL}	$V_{IN} = V_{IH}$	I _{OL} = 100 μA	1.2	_	0.05	
Input leakage curr	rent	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.2		±5.0	μA
Power-off leakage	current	IOFF	V_{IN} , $V_{OUT} = 0$ to 3.6 V	V _{IN} , V _{OUT} = 0 to 3.6 V		_	10.0	μA
Ouissesst sugglu suggest		Icc	$V_{IN} = V_{CC}$ or GND		1.2		20.0	
Quiescent supply	Quiescent supply current		$V_{CC} \leq V_{IN} \leq 3.6 \text{ V}$	$V_{CC} \leq V_{IN} \leq 3.6 \text{ V}$			±20.0	μA

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns) (Note 1)

Characteristics	Symbol	Test Condition			Min	Max	Unit
				1.2	1.5	37.0	
			$C_{I} = 15 pF, R_{I} = 2 k\Omega$	1.2	1.5	37.0	
	t			1.5 ± 0.1	1.0	14.8	
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2		1.8 ± 0.15	1.5	7.4	ns
	φnL		$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	2.5 ± 0.2	0.8	3.7	
				$\textbf{3.3}\pm\textbf{0.3}$	0.6	2.8	
			CL = 15 pF, RL = 2 kΩ	1.2	—	1.5	
	•			1.5 ± 0.1	—	1.5	
Output to output skew	t _{osLH}	(Note 2)		1.8 ± 0.15	—	0.5	ns
	t _{osHL}		$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	2.5 ± 0.2	—	0.5	
				$\textbf{3.3}\pm\textbf{0.3}$	—	0.5	

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Symbol	Test Condition		Тур.	Unit	
	-,			$V_{CC}\left(V\right)$		
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ ((Note)	1.8	0.25	
Quiet output maximum dynamic V_{OL}	V _{OLP}	$V_{IH} = 2.5 V, V_{IL} = 0 V$ ((Note)	2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ ((Note)	3.3	0.8	
	V _{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ ((Note)	1.8	-0.25	
Quiet output minimum dynamic V_{OL}		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ ((Note)	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ ((Note)	3.3	-0.8	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ ((Note)	1.8	1.5	
Quiet output minimum dynamic V _{OH}		$V_{IH} = 2.5 V, V_{IL} = 0$ ((Note)	2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ ((Note)	3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition			Тур.	Unit
Characteristics	Symbol	Test Condition	V _{CC} (V)	тур.	Unit	
Input capacitance	C _{IN}	_		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$ (per gate)

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AC Test Circuit

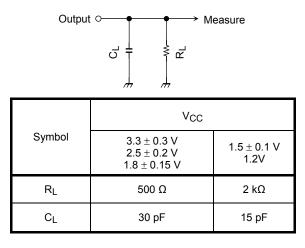
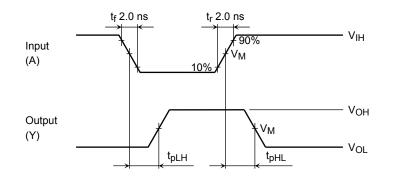


Figure 1

AC Waveform



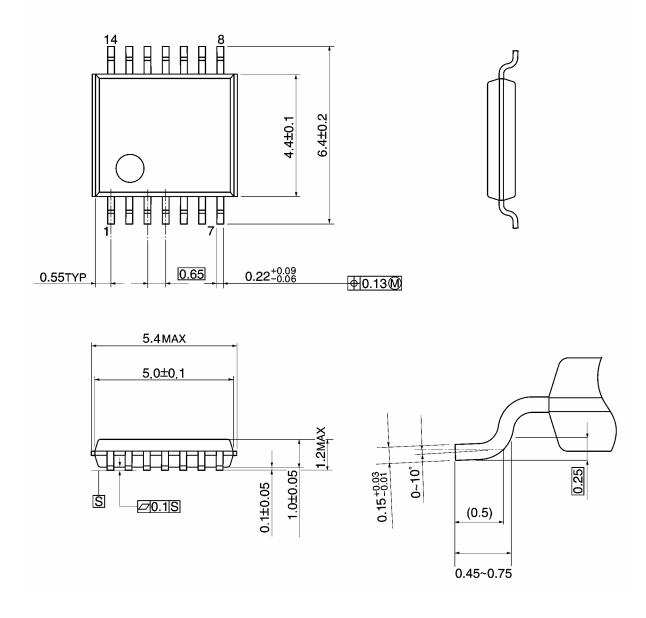
Symbol	V _{CC}				
	$3.3\pm0.3\;V$	$2.5\pm0.2\;V$	$1.8\pm0.15~V$	$1.5\pm0.1~\text{V}$	1.2 V
VIH	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}
VM	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2

Figure 2 tpLH, tpHL

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



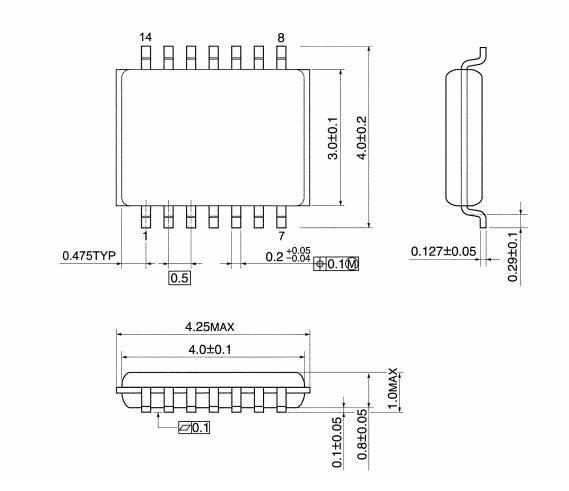
Weight: 0.06 g (typ.)

TOSHIBA

Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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